

#### 20V N-Channel Enhancement Mode MOSFET

Voltage 20 V Current 6.0A

#### **Features**

- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_{D}@6.0A<25m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@2.5V$ ,  $I_{D}@4.8A<36m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@1.8V$ ,  $I_{D}@3.5A<45m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM

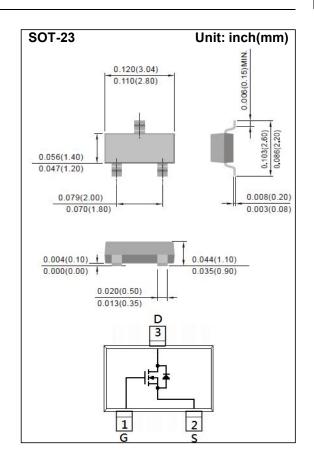
Application, etc

#### **Mechanical Data**

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams



## **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	20	V	
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 12		
Continuous Drain Current		I <sub>D</sub>	6.0	A	
Pulsed Drain Current		I <sub>DM</sub>	16.4		
Power Dissipation	T <sub>a</sub> =25°C	Б	1.25	W	
	Derate above 25°C	P <sub>D</sub>	10	mW/ °C	
Operating Junction and Storage Temperature Range		$T_{J}, T_{STG}$	-55~150	°C	
Typical Thermal Resistance					
Junction to Ambient (Note 3)		$R_{\theta JA}$	100	°C/W	



# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	0.4	0.66	1.2	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =6.0A	-	21	25	mΩ
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =4.8A	-	30	36	
		V <sub>GS</sub> =1.8V, I <sub>D</sub> =3.5A	-	36	45	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 5)						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =10V, I <sub>D</sub> =6.0A, V <sub>GS</sub> =4.5V <sup>(Note 1,2)</sup>	-	4.6	-	nC
Gate-Source Charge	$Q_gs$		-	0.8	-	
Gate-Drain Charge	$Q_{gd}$		-	1	-	
Input Capacitance	Ciss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHZ	-	350	-	pF
Output Capacitance	Coss		-	40	-	
Reverse Transfer Capacitance	Crss		-	29	-	
Turn-On Delay Time	td <sub>(on)</sub>	V <sub>DD</sub> =10V, I <sub>D</sub> =6.0A, V <sub>GS</sub> =4.5V,	-	4	-	
Turn-On Rise Time	tr		-	47	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	18	-	
Turn-Off Fall Time	tf	$R_G=6\Omega$ (Note 1,2)	-	10	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					4.5	
Diode Forward Current	Is		_	_	1.5	A
Diode Forward Voltage	$V_{\mathtt{SD}}$	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.75	1.2	V

#### NOTES:

- 1. Pulse width < 300us, Duty cycle < 2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





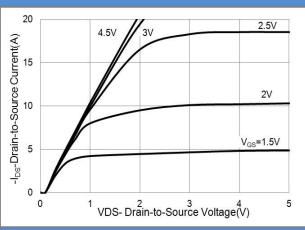
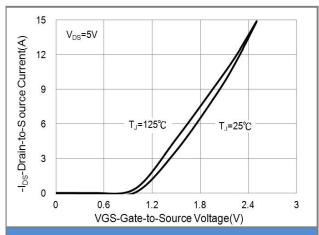


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

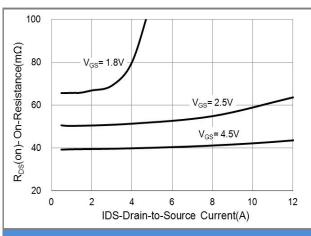


Fig.3 On-Resistance vs. Drain Current

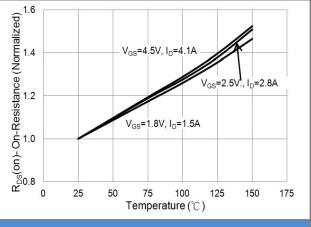


Fig.4 On-Resistance vs. Junction temperature

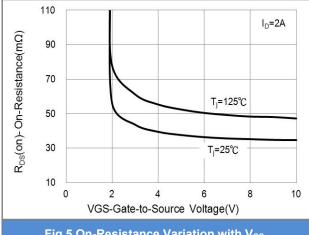


Fig.5 On-Resistance Variation with V<sub>GS</sub>

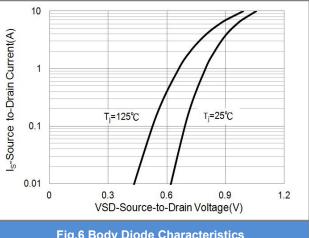


Fig.6 Body Diode Characteristics



Gate-Source Voltage-V<sub>GS</sub>(Volts)

1

0

0

# CSM2312S23

# TYPICAL CHARACTERISTIC CURVES 5 V<sub>DS</sub>= 10V ID=4.1A

Fig.7 Gate-Charge Characteristics

Qg(nC)

2

1

3

4

5

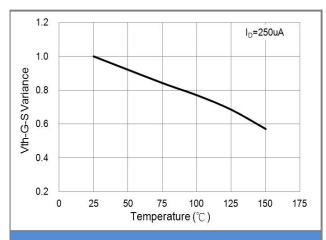


Fig.8 Threshold Voltage Variation with Temperature

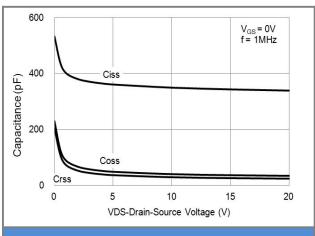


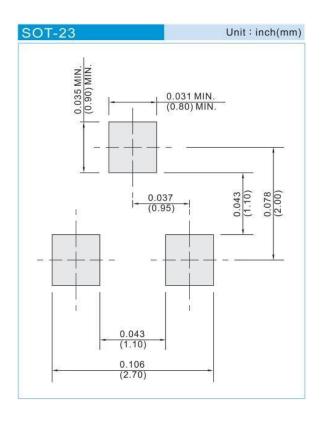
Fig.9 Capacitance vs. Drain-Source Voltage



## **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type
CSM2312S23	SOT-23	3K pcs / 7" reel

## **Mounting Pad Layout**





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